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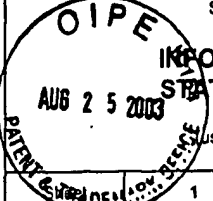


PTO/SB/08A (08-00)

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Substitute for Form 1449A/PTO		Complete If Known	
 <p>INFORMATION DISCLOSURE STATEMENT BY APPLICANT</p> <p>Use as many sheets as necessary)</p>		Application Number	10/632,230
		Filing Date	July 31, 2003
		First Named Inventor	Colombo et al.
		Group Art Unit	
		Examiner Name	
1	of	1	Attorney Docket No. TI-35230

U.S. PATENT DOCUMENTS						
Exam. Initials*	Cite No. ¹	U.S. Patent Document		Name of Patentee or Applicant of Cited Doc.	Date of Pub. of Cited Doc. (mm-dd-yyyy)	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
		Number	Kind Code ² (if known)			
al	AA	2003/0080389	A1	Hu et al.	05/01/2003	Entire Document
	AB					
	AC					
	AD					
	AE					
	AF					
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FOREIGN PATENT DOCUMENTS							
Exam. Initials*	Cite No. ¹	Foreign Patent Document			Name of Patentee or Applicant of Cited Doc.	Date of Pub. of Cited Doc. (mm-dd-yyyy)	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
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al	CA	"Fabrication of HfSiON Gate Dielectrics by Plasma Oxidation and Nitridation, Optimized for 65nm node Low Power CMOS Applications, SEIJI INUMIYA, KATSUYUKI SEKINE, SHOKO NIWA, AKIO KANEKO, MOTOYUKI SATO, TAKESHI WATANABE, HIRONOBU FUKUI, YOSHIKI KAMATA, MASATO KOYAMA AKIRA NISHIYAMA, MARIKO TAKAYANAGI, KAZUHIRO EGUCHI and YOSHITAKA TSUNASHIMA, 2003 Symposium on VLSI Technology Digest of Technical Papers, June, 2003, 2 pgs.		
	CB			
	CC			
	CD			
	CE			
	CF			
	CG			
	CH			

Examiner Signature		Date Considered	04/20/04
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				Group Art Unit	
Examiner Name					
Sheet	1	of	1	Attorney Docket No.	TI-35230

U.S. PATENT DOCUMENTS						
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		Number	Kind Code ² (if known)			
AL	AA	5,352,623		Kamiyama	10/04/1994	Entire Document
	AB	5,910,880		DeBoer et al.	06/08/1999	Entire Document
	AC	6,013,553		Wallace et al.	01/11/2000	Entire Document
	AD	6,015,739		Gardner et al.	01/18/2000	Entire Document
	AF	6,020,243		Wallace et al.	02/01/2000	Entire Document
	AG	6,136,654		Kraft et al.	10/24/2000	Entire Document
	AH	6,251,761	B1	Rodder et al.	06/26/2001	Entire Document
	AJ	6,291,866	B1	Wallace et al.	09/18/2001	Entire Document
	AK	6,291,867	B1	Wallace et al.	09/18/2001	Entire Document
AL	AL	6,436,801	B1	Wilk et al.	08/20/2002	Entire Document

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	CA			
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	CC			
	CD			
	CE			
	CF			
	CG			
	CH			

Examiner Signature	<i>Anders Murray</i>	Date Considered	02/30/02
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